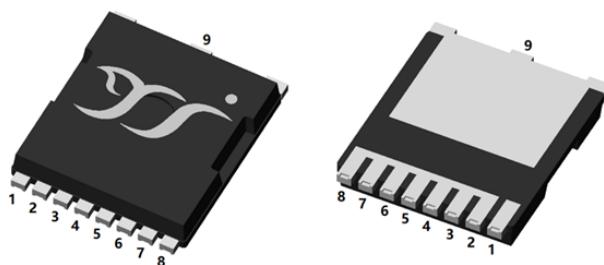


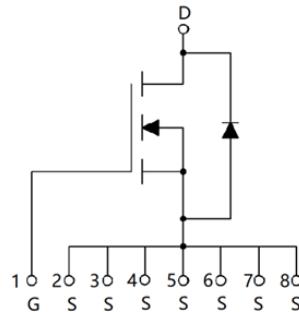


N-Channel Enhancement Mode Field Effect Transistor



Top View

Bottom View

TOLL

Product Summary

- V_{DS} 40V
- I_D (Chip limitation) 639A
- $R_{DS(ON)}$ (at $V_{GS}=10V$) $<0.6m\Omega$
- 100% EAS Tested
- 100% ∇V_{DS} Tested

General Description

- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- Power switching application
- Uninterruptible power supply
- DC-DC convertor

■ Limiting Values

| Parameter | Conditions | | Symbol | Min | Max | Unit |
|--|--|---|----------------|-----|--------|------|
| Drain-source Voltage | | | V_{DS} | - | 40 | V |
| Gate-source Voltage | | | V_{GS} | -20 | 20 | |
| Continuous Drain Current (Note 1,2) | Steady-State | $T_A=25^\circ C, V_{GS}= 10V$ | I_D | - | 59 | A |
| | | $T_A=100^\circ C, V_{GS}= 10V$ | | - | 42 | |
| Continuous Drain Current (Note 1,3) | Steady-State | $T_c=25^\circ C, V_{GS}= 10V$, Chip limitation | | - | 639 | |
| | | $T_c=100^\circ C, V_{GS}= 10V$ | | - | 452 | |
| Pulsed Drain Current | $T_c=25^\circ C, t_p \leq 10\mu s$ | | I_{DM} | - | 2100 | |
| Maximum Body-Diode Continuous Current | $T_c=25^\circ C$ | | I_S | | 350 | |
| Avalanche energy (non-repetitive) | $T_J=25^\circ C, V_G=10V, R_G=25\Omega, L=1mH, I_{AS}=77A$ | | EAS | - | 2964.5 | mJ |
| Total Power Dissipation (Note 1,2) | Steady-State | $T_A=25^\circ C$ | P_D | - | 3.6 | W |
| | | $T_A=100^\circ C$ | | - | 1.8 | |
| Total Power Dissipation (Note 1,3) | Steady-State | $T_c=25^\circ C$ | | - | 429 | |
| | | $T_c=100^\circ C$ | | - | 214 | |
| Junction and Storage Temperature Range | | | T_J, T_{STG} | -55 | 175 | °C |

■ Thermal Resistance

| Parameter | Symbol | Typ | Max | Units |
|---|-----------------|-----|------|-------|
| Thermal Resistance Junction-to-Ambient (Note 2) | $R_{\theta JA}$ | - | 41.2 | °C/W |
| Thermal Resistance Junction-to-Case | $R_{\theta JC}$ | - | 0.35 | |

■ Ordering Information (Example)

| PREFERRED P/N | PACKING CODE | Marking | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|---------------|--------------|------------|----------------------|-------------------------|----------------------------|---------------|
| YJT0D6G04H | F1 | YJT0D6G04H | 2000 | 4000 | 20000 | 13" reel |



■ Electrical Characteristics

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
|-----------------------------------|---------------------|---|-----|-------|------|-------|
| Static Parameter | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250μA, T _j =25°C | 40 | - | - | V |
| | | V _{GS} =0V, I _D =1mA, T _j =25°C | 40 | - | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =40V, V _{GS} =0V, T _j =25°C | - | - | 1 | μA |
| | | V _{DS} =40V, V _{GS} =0V, T _j =125°C | - | - | 100 | |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} =±20V, V _{DS} =0V, T _j =25°C | - | - | ±100 | nA |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250μA, T _j =25°C | 2.1 | 2.9 | 3.7 | V |
| Static Drain-Source On-Resistance | R _{DS(on)} | V _{GS} =10V, I _D =50A, T _j =25°C | - | 0.39 | 0.6 | mΩ |
| Diode Forward Voltage | V _{SD} | I _S =50A, V _{GS} =0V, T _j =25°C | - | 0.77 | 1.2 | V |
| Gate Resistance | R _G | f=1MHz, T _j =25°C | - | 1.15 | - | Ω |
| Dynamic Parameters | | | | | | |
| Input Capacitance | C _{iss} | V _{DS} =20V, V _{GS} =0V, f=1MHz, T _j =25°C | - | 19547 | - | pF |
| Output Capacitance | C _{oss} | | - | 6480 | - | |
| Reverse Transfer Capacitance | C _{rss} | | - | 138 | - | |
| Switching Parameters | | | | | | |
| Total Gate Charge | Q _g | V _{GS} =10V, V _{DS} =20V, I _D =50A, T _j =25°C | - | 255.7 | - | nC |
| Gate-Source Charge | Q _{gs} | | - | 80.6 | - | |
| Gate-Drain Charge | Q _{gd} | | - | 47.4 | - | |
| Reverse Recovery Charge | Q _{rr} | I _F =50A, di/dt=100A/μs, V _{GS} =0V, V _R =20V, T _j =25°C | - | 133 | - | nC |
| Reverse Recovery Time | t _{rr} | | - | 85.5 | - | ns |
| Turn-on Delay Time | t _{D(on)} | V _{GS} =10V, V _{DS} =20V, I _D =50A, R _{GEN} =3Ω, T _j =25°C | - | 50.5 | - | ns |
| Turn-on Rise Time | t _r | | - | 118.7 | - | |
| Turn-off Delay Time | t _{D(off)} | | - | 126.8 | - | |
| Turn-off Fall Time | t _f | | - | 63 | - | |

Note:

- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- The value of R_{θJA} is measured with the device mounted on the 40mm*40mm*1.1mm single layer FR-4 PCB board with 1 in² pad of 2oz. Copper, in the still air environment with T_A=25°C. The maximum allowed junction temperature of 175°C. The value in any given application depends on the user's specific board design.
- Thermal resistance from junction to soldering point (on the exposed drain pad).

■Typical Electrical and Thermal Characteristics Diagrams

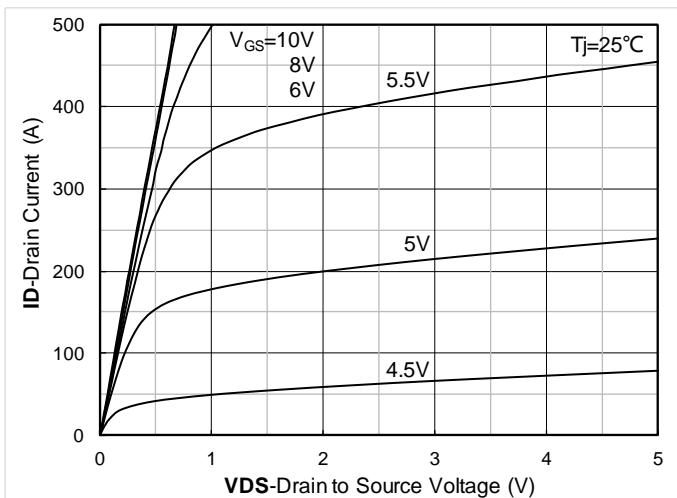


Figure 1. Output Characteristics; typical values

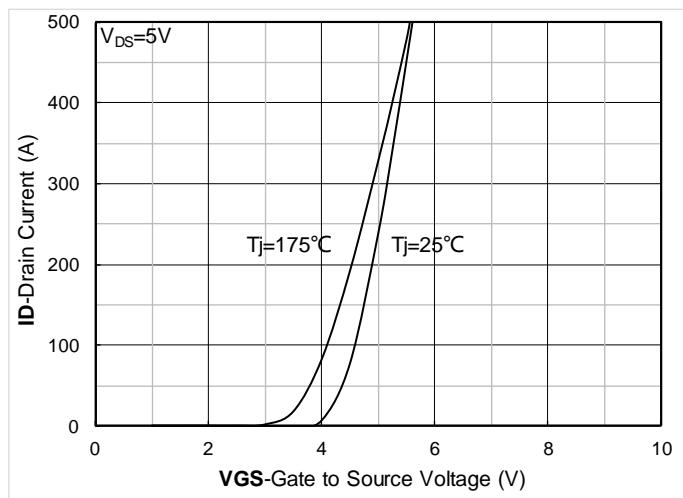


Figure 2. Transfer Characteristics; typical values

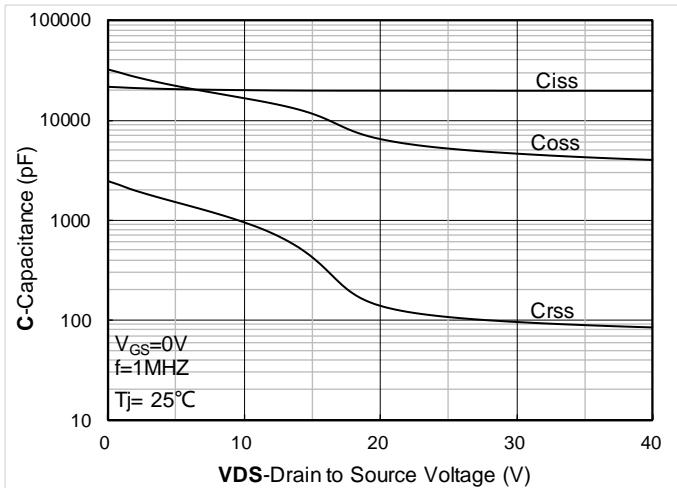


Figure 3. Capacitance Characteristics; typical values

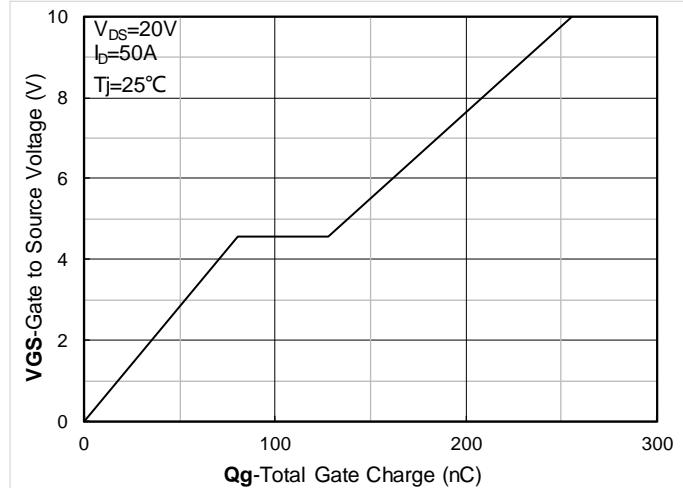


Figure 4. Gate Charge; typical values

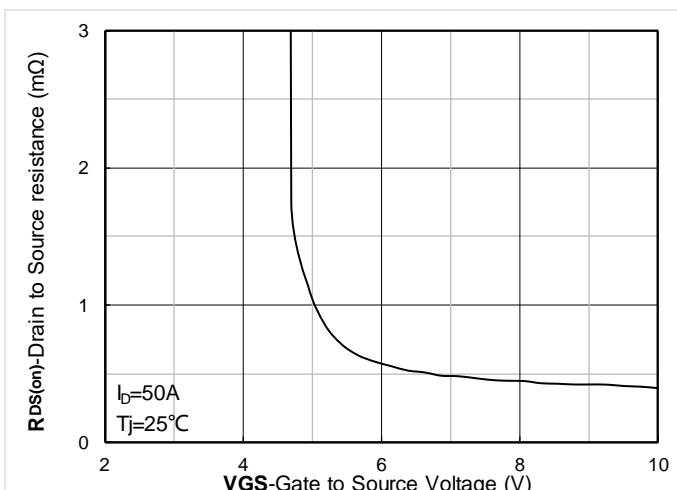


Figure 5. On-Resistance vs. Gate to Source Voltage; typical values

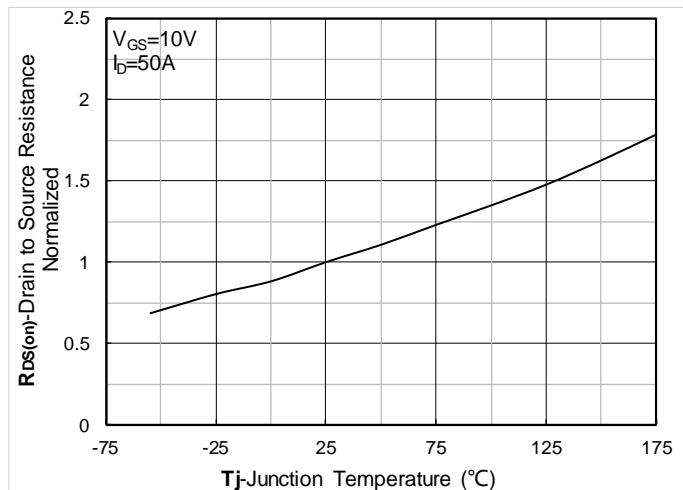


Figure 6. Normalized On-Resistance

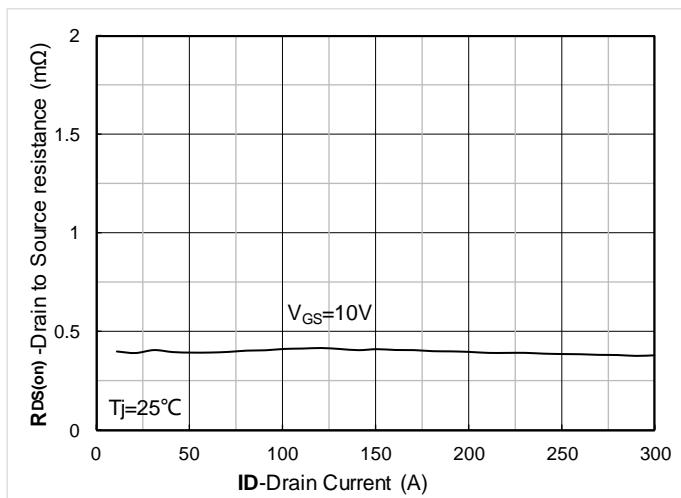
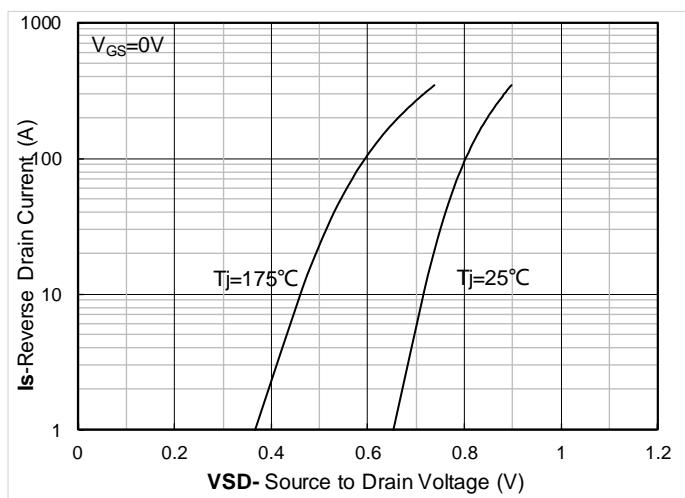
Figure 7. $R_{DS(on)}$ vs. Drain Current; typical values

Figure 8. Forward characteristics of reverse diode; typical values

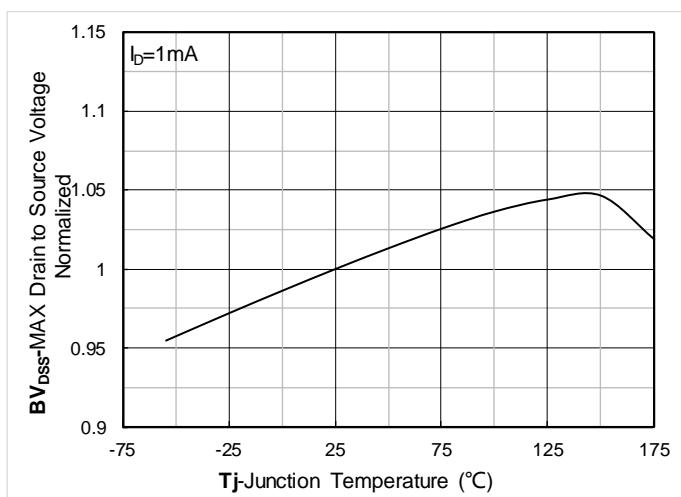


Figure 9. Normalized breakdown voltage

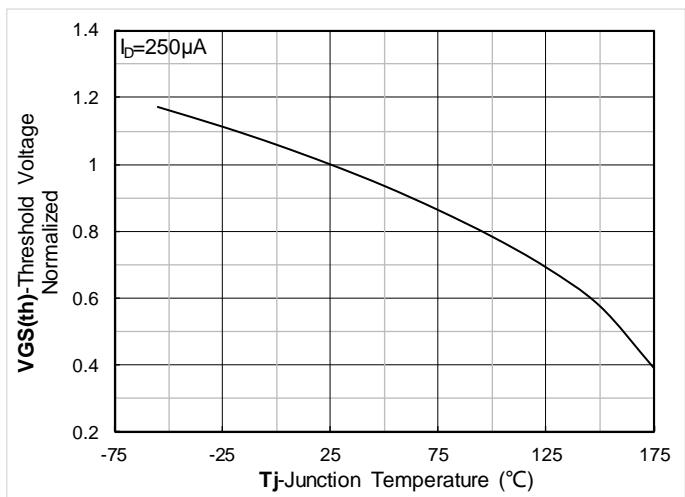


Figure 10. Normalized Threshold voltage

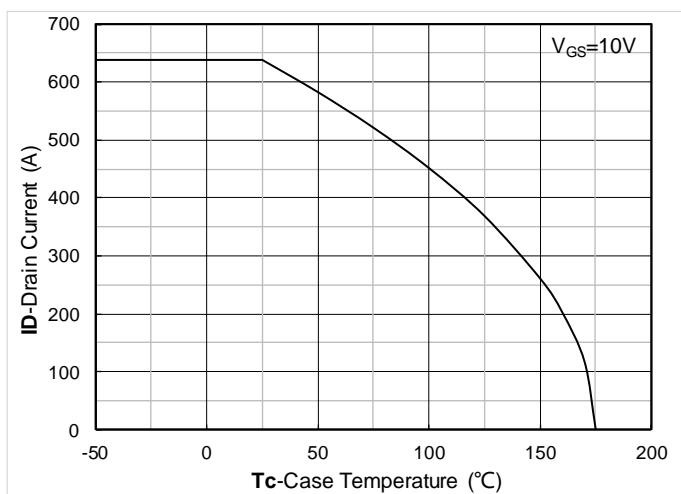


Figure 11. Current dissipation

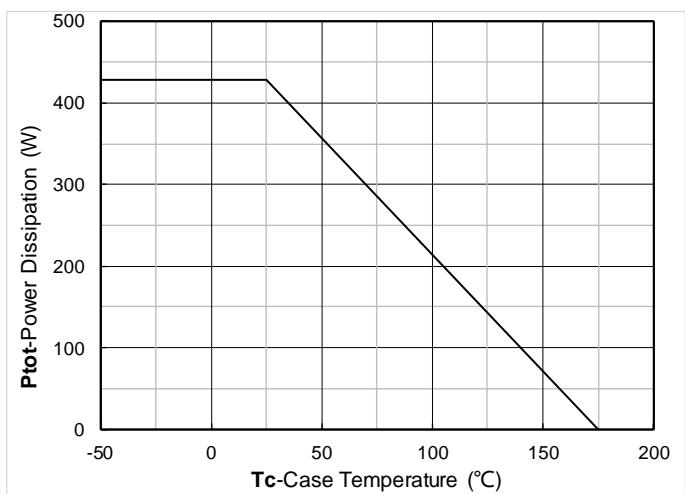


Figure 12. Power dissipation

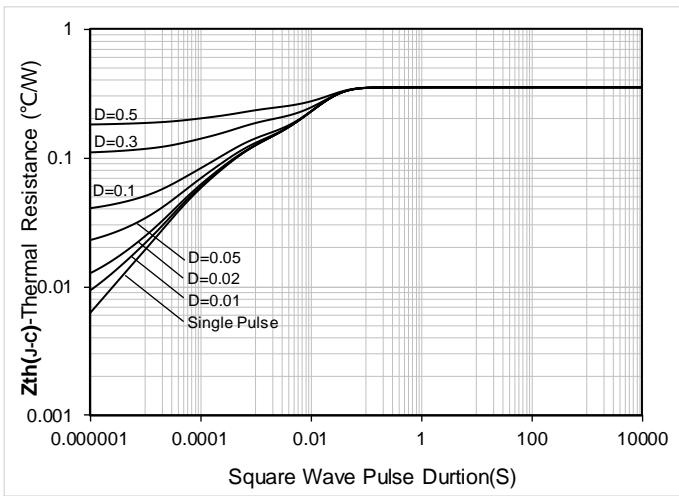


Figure 13. Maximum Transient Thermal Impedance

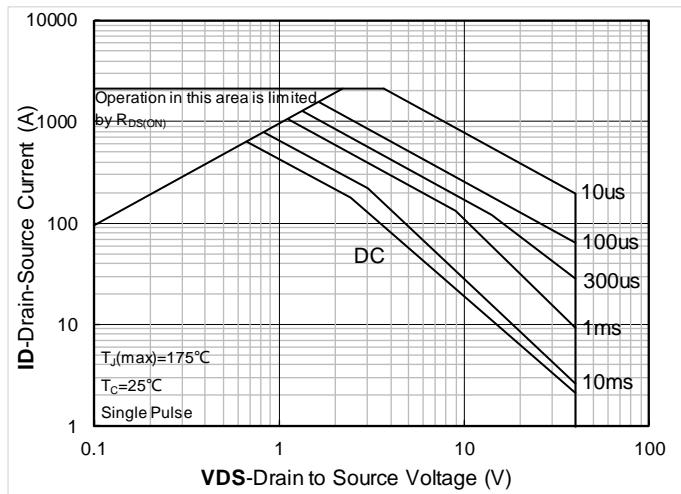


Figure 14. Safe Operation Area

■ Test Circuits & Waveforms

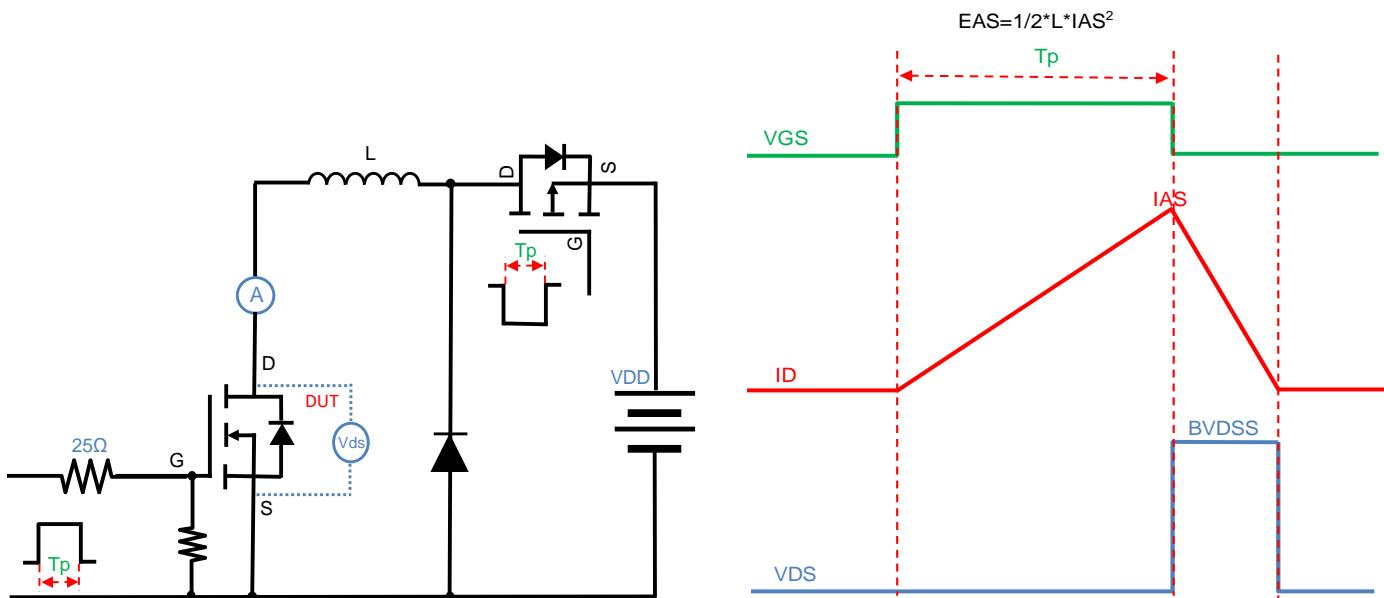


Figure A. Unclamped Inductive Switching (UIS) Test Circuit & Waveform

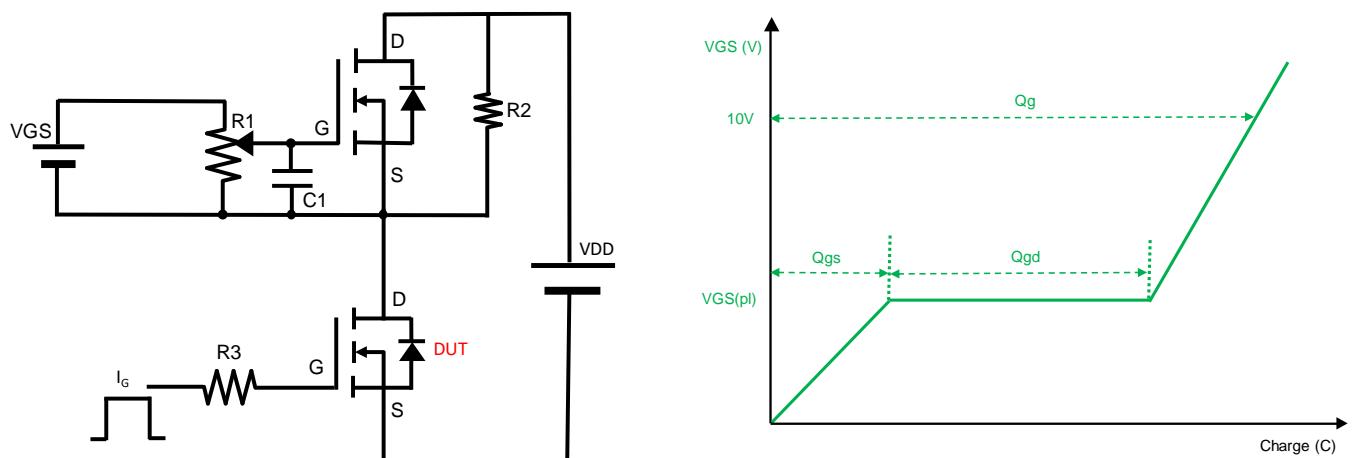


Figure B. Gate Charge Test Circuit & Waveform

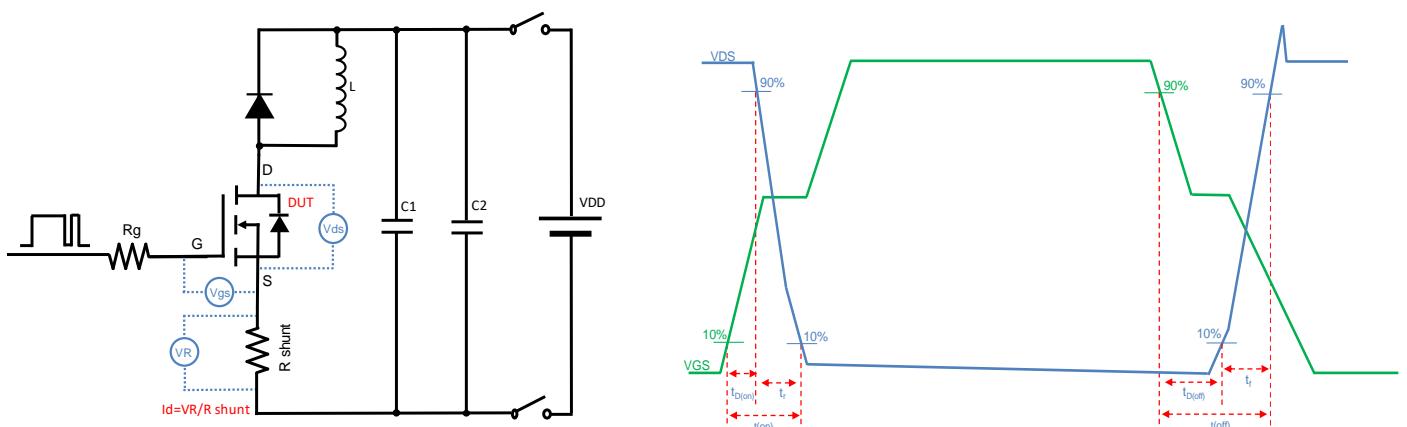


Figure C. Resistive Switching Test Circuit & Waveform

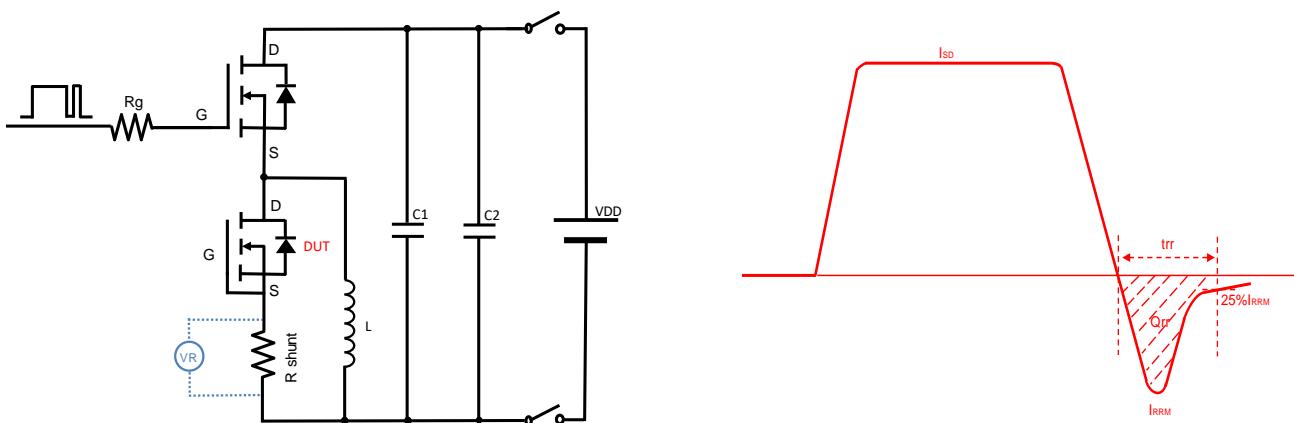
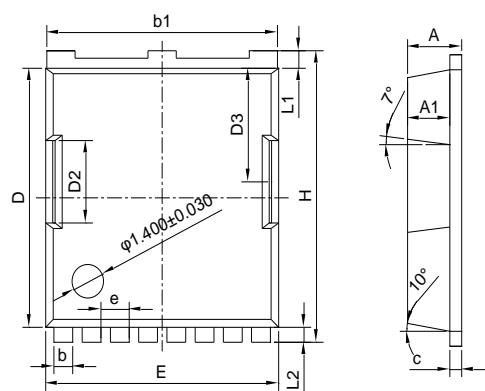


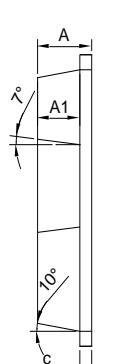
Figure D. Diode Recovery Test Circuit & Waveform



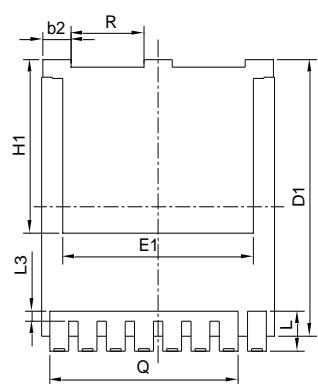
■ TOLL Package information



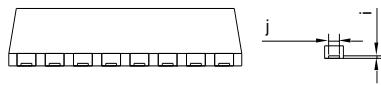
TOP VIEW



SIDE VIEW

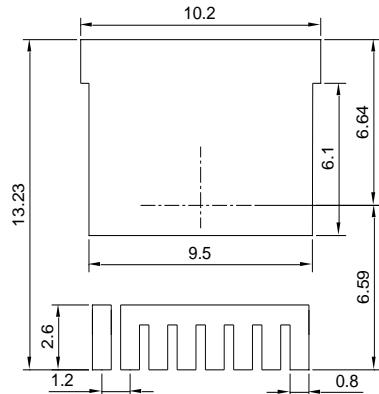


BOTTOM VIEW



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ±0.03mm.
3. The pad layout is for reference purposes only.

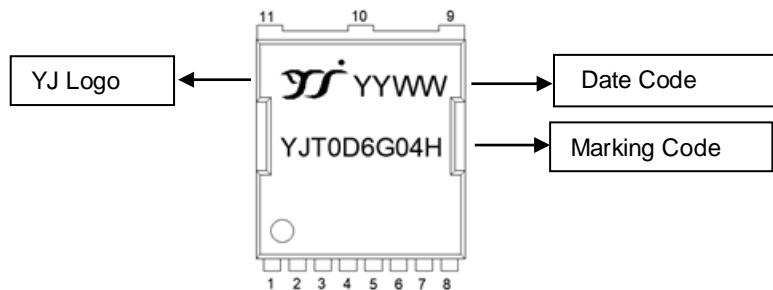
SUGGESTED SOLDER PAD LAYOUT
TOP VIEW

| SYMBOL | MILLIMETER | | |
|--------|------------|----------|-------|
| | MIN | NOM | MAX |
| A | 2.2 | 2.3 | 2.4 |
| A1 | 1.7 | 1.8 | 1.9 |
| b | 0.7 | 0.8 | 0.9 |
| b1 | 9.7 | 9.8 | 9.9 |
| b2 | 1.1 | 1.2 | 1.3 |
| c | 0.4 | 0.5 | 0.6 |
| D | 10.28 | 10.38 | 10.48 |
| D1 | 10.98 | 11.08 | 11.18 |
| D2 | 3.2 | 3.3 | 3.4 |
| D3 | 4.45 | 4.55 | 4.65 |
| E | 9.8 | 9.9 | 10 |
| E1 | 8 | 8.1 | 8.2 |
| e | | 1.2 BSC | |
| H | 11.58 | 11.68 | 11.78 |
| H1 | | 6.95 BSC | |
| i | | 0.1 REF | |
| j | | 0.46 REF | |
| L | 1.5 | 1.6 | 1.7 |
| L1 | 0.6 | 0.7 | 0.8 |
| L2 | 0.5 | 0.6 | 0.7 |
| L3 | 0.3 | 0.4 | 0.5 |
| Q | | 8 REF | |
| R | 3.0 | 3.1 | 3.2 |

UNIT: mm



■ Marking Information



Note:

1. All marking is at middle of the product body
2. All marking is in laser printing
3. YJT0D6G04H is Marking Code, YYWW is date code, "YY" is year, "WW" is week
4. Body color: Black



Disclaimer

The information presented in this document is for reference only. Yangzhou Yangjie Electronic Technology Co., Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Yangjie or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use or sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website <http://www.21yangjie.com>, or consult your nearest Yangjie's sales office for further assistance.